Lecture 11 2023/2024 Microwave Devices and Circuits for Radiocommunications

2023/2024

- 2C/1L, MDCR
- Attendance at minimum 7 sessions (course or laboratory)
- Lectures- associate professor Radu Damian
 - Tuesday 16-18, Online, P8
 - E 50% final grade
 - problems + (2p atten. lect.) + (3 tests) + (bonus activity)
 - first test L1: 20-27.02.2024 (t2 and t3 not announced, lecture)
 - 3att.=+0.5p
 - all materials/equipments authorized

2023/2024

- Laboratory associate professor Radu Damian
 - Tuesday 08-12, II.13 / (08:10)
 - L 25% final grade
 - ADS, 4 sessions
 - Attendance + personal results
 - P 25% final grade
 - ADS, 3 sessions (-1? 20.02.2024)
 - personal homework

Materials

http://rf-opto.etti.tuiasi.ro

🔹 Laborator	ul de Microunde si Op: x +					
$\leftrightarrow \ \ $	Not secure rf-opto.etti.tuiasi.ro/microwave_cd.php?chg_lang=0					☆ 🖪
	Main <u>Courses</u> Master Staff Research Students Admin					
	Microwave CD Optical Communications Optoelectronics Internet Antennas Practica Networks Educ	ational software				
	Microwave Devices and Circuits for Radiocommunications (Er	iglish)				
	Course: MDCR (2017-2018)					
	Course Coordinator: Assoc.P. Dr. Radu-Florin Damian					
	Ciscipline Type: DOS; Alternative, Specialty Credits: 4					Ten
	Enrollment Year: 4, Sem. 7	dest	DE			
	Activities	(ETTIX)				
	Course: Instructor: Assoc.P. Dr. Radu-Florin Damian, 2 Hours/Week, Specialization Section, Timetable: Laboratory: Instructor: Assoc.P. Dr. Radu-Florin Damian, 1 Hours/Week, Group, Timetable:	Res V			1	N 2 1
	Evaluation	1 al				1812 LASI
	Type: Examen					
	A: 50%, (Test/Colloquium) B: 25%, (Seminary/Laboratory/Project Activity) D: 25%, (Homework/Specialty papers)		Romana			
	Grades	Main	Courses	Mactor	Staff	Dec
	Aggregate Results	Piain	Courses	Master	Stall	Res
	Attendance	1144 - 64	Sector in Mass in	وليتيل ا		
	Course	Grades	Student List	<u>Exams</u>	Photos	
	LISLS Roque uni computato (final)	- I' -				
	Studenti care nu pot intra in examen	Online Ex	ams			
	Materials					-
	Course Slides	In order to partic	cipate at online e	xams you mu	st get ready	following

On the

-1-

4

Control 1

<u>MDCR Lecture 1</u> (pdf, 5.43 MB, en, 38) <u>MDCR Lecture 2</u> (pdf, 3.67 MB, en, 38) <u>MDCR Lecture 3</u> (pdf, 4.76 MB, en, 38) MDCR Lecture 4 (pdf, 5.58 MB, en, 38)





Microwave and Optoelectronics Laboratory

We are enlisted in the Telecommunications Department of the Electronics, Telecommunication and Information Technology Faculty (ETTI) from the "Gh. Asachi" Technical University (TUIASI) in Iasi, Romania

We currently cover inside ETTI the fields related to:

- Microwave Circuits and Devices
- Optoelectronics
- Information Technology

Courses

Nr.	Course	Shortcut	Code	Туре	Semester	Credits	Weekly	Examination	Link			
1	Microwave Devices and Circuits for Radiocommunications	DCMR	DOS412T	DOS	7	4	0P,1L,0S,2C	Exam	details			
2	Monolithic Microwave Integrated Circuits	CIMM	1 RD.IA.207 DOMS 11 6 1.5L,0S,2C,0				1.5L,0S,2C,0P	Exam	details			
3	Advanced Techniques in the Design of the Radio-communications Systems	TAPSR	APSR RD.IA.103 DIMS 9 6 1.5P,0L,0S,2				1.5P,0L,0S,2C	Exam deta				
4	Optical Communications	CO	D DOS409T DOS 7 5 0P,1L,0S,3				0P,1L,0S,3C	Colloquium details				
5	Optical Communications	OC	EDOS409T	DOS	7	5	0P,1L,0S,3C	Exam	details			
6	Satellite Communications	CS	RC.IA.104	DIMS	9	6	0L,0S,2C,1.5P	Exam	details			
7	Applied Informatics 1	IA1	1 DOF135 DOF 1 4 0P,1L,0		0P,1L,0S,2C	Verification	details					
8	Applied Informatics 1	AI1	I1 EDOF135 DOF 1 4 0P,1L,0S,20		0P,1L,0S,2C	Verification	details					
9	Databases, Web Programming and Interfacing	DWPI	ITT.IA.601	DIS	11	5	1P,1L,0.25S,1C	Verification	details			
10	Web Applications Design	PAW	RC.IA.108	DIMS	10	5	1L,0S,1.5C,1P	Exam	details			
11	Optoelectronics	ОРТО	DID405M	DID	8	4	0P,1L,0S,2C	Colloquium	details			
12	Microwave Devices and Circuits for Radiocommunications (English)	MDCR	EDOS412T	DOS	8	4	0P,1L,0S,2C	Exam	details			



Materials

RF-OPTO

- http://rf-opto.etti.tuiasi.ro
- David Pozar, "Microwave Engineering", Wiley; 4th edition, 2011
 - 1 exam problem ← Pozar

Photos

- sent by email/online exam > Week4-Week6
- used at lectures/laboratory

Online – Registration no.

access to online exams requires the password received by email

The password is communicated during the lectures. It is necessary





Password

received by email

Important message from RF-OPTO

Radu-Florin Damian

to me, POPESCU 🔻

☆ Romanian - > English - Translate message



Laboratorul de Microunde si Optoelectronica Facultatea de Electronica, Telecomunicatii si Tehnologia Informatiei Universitatea Tehnica "Gh. Asachi" Iasi

In atentia: POPESCU GOPO ION

Parola pentru a accesa examenele pe server-ul rf-opto este Parola:

Identificati-va pe server, cu parola, cat mai rapid, pentru confirmare.

Memorati acest mesaj intr-un loc sigur, pentru utilizare ulterioara

Attention: POPESCU GOPO ION

The password to access the exams on the rf-opto server is Password:

Login to the server, with this password, as soon as possible, for confirmation.

Save this message in a safe place for later use

Reply

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Attention: POPESCU GOPO ION

The password to access the exams on the **rf-opto** server is Password:

Login to the server, with this password, as soon as possible, for confirmation.

Save this message in a safe place for later use

Online exam manual

- The online exam app used for:
 - Iectures (attendance)
 - Iaboratory
 - project
 - examinations



Examen online

always against a timetable

long period (lecture attendance/laboratory results)

short period (tests: 15min, exam: 2h)



Online results submission

many numerical values/files

Schema finala	Rezultate - castig	Rezultate - zgomot	Fisier justificare calcul (factor andrei)	Fisier zap (optional)	T1, fisier parmetri S	T2, fisier parmetri S	Z1	Z 2	Z 3	Z4	Z5	Z6	27	Ze1	Z01	Ze2	Zo2	Ze3	Zo3	Ze4	Zo4	Ze5	Zo5	Zei
<u>86 -</u> 5428 - 259	<u>86 -</u> 5428 - 260	<u>86 -</u> 5428 - 261	<u>86 -</u> <u>5428 -</u> <u>316</u>		<u>86 -</u> <u>5428 -</u> <u>314</u>	<u>86 -</u> <u>5428 -</u> <u>315</u>	148.33	155.88	202.12	164.35	180.91	30.29	185.19	79 <mark>.</mark> 9	37	68.89	45.14	61.83	45.05	57.97	46.02	61.85	45.05	68.
<u>86 -</u> <u>5622 -</u> <u>259</u>	<u>86 -</u> <u>5622 -</u> <u>260</u>	<u>86 -</u> <u>5622 -</u> <u>261</u>	<u>86 -</u> <u>5622 -</u> <u>316</u>	<u>86 -</u> <u>5622 -</u> <u>262</u>	<u>86 -</u> <u>5622 -</u> <u>314</u>	<u>86 -</u> <u>5622 -</u> <u>315</u>	26.97	153.5	34.64	35.79	55.56	26.212	10.693	0	0	0	0	0	0	0	0	0	0	0
<u>86 -</u> <u>5488 -</u> <u>259</u>	<u>86 -</u> <u>5488 -</u> <u>260</u>	<u>86 -</u> <u>5488 -</u> <u>261</u>	<u>86 -</u> 5488 - <u>316</u>	<u>86 -</u> <u>5488 -</u> <u>262</u>	<u>86 -</u> <u>5488 -</u> <u>314</u>	<u>86 -</u> <u>5488 -</u> <u>315</u>	0	0	0	0	0	0	0	o	0	0	0	0	0	0	0	0	0	0
<u>86 -</u> <u>5391 -</u> <u>259</u>	<u>86 -</u> 5391 - 260	<u>86 -</u> <u>5391 -</u> <u>261</u>	<u>86 -</u> 5391 - <u>316</u>	-	-		50	50	50	50	50	50	50	70.14	40.39	61.85	44.59	55.7	45.2	54.89	45.38	58.65	45.8	70.
<u>86 -</u> <u>5664 -</u> <u>259</u>	<u>86 -</u> <u>5664 -</u> <u>260</u>	<u>86 -</u> <u>5664 -</u> <u>261</u>	86 - 5664 - 316	8	<u>86 -</u> <u>5664 -</u> <u>314</u>	<u>86 -</u> <u>5664 -</u> <u>315</u>	168.02	150.5	178.28	133.75	92.12	121.67	144.48	94 <mark>.</mark> 36	36.19	70.77	42.56	65.69	42.05	55.17	42.29	65.59	42.05	70.
<u>86 -</u> <u>5665 -</u> <u>259</u>	<u>86 -</u> <u>5665 -</u> <u>260</u>	<u>86 -</u> <u>5665 -</u> <u>261</u>	<u>86 -</u> <u>5665 -</u> <u>316</u>	-	<u>86 -</u> <u>5665 -</u> <u>314</u>	<u>86 -</u> <u>5665 -</u> <u>315</u>	162.2	80.8	209.2	140.85	135.1	183.7	167.6	94.58	36.15	78.16	39.77	65.57	45.05	65.57	45.05	78.16	39.77	94.
<u>86 -</u> <u>5433 -</u> <u>259</u>	<u>86 -</u> 5433 - 260	86 - 5433 - 261	86 - 5433 - 316		<u>86 -</u> <u>5433 -</u> <u>314</u>	<u>86 -</u> <u>5433 -</u> <u>315</u>	165.138	106.228	226.157	130.134	72.71	180.177	164.616	101.36	36.11	77.22	42.49	68.02	45.62	60	45.42	68.02	45.62	77.
<u>86 -</u> <u>5608 -</u> <u>259</u>	<u>86 -</u> <u>5608 -</u> <u>260</u>	<u>86 -</u> <u>5608 -</u> <u>261</u>	<u>86 -</u> <u>5608 -</u> <u>316</u>	-	<u>86 -</u> <u>5608 -</u> <u>314</u>	<u>86 -</u> <u>5608 -</u> <u>315</u>	150.84	152.5	30.94	32.37	54.36	19.837	29.85	64.14	40.145	54.32	46.32	53.8	46.7	53.8	46.7	54.32	46.32	54.
<u>86 -</u> <u>5555 -</u> <u>259</u>	<u>86 -</u> <u>5555 -</u> <u>260</u>	86 - 5555 - 261	<u>86 -</u> <u>5555 -</u> <u>316</u>		<u>86 -</u> <u>5555 -</u> <u>314</u>	<u>86 -</u> <u>5555 -</u> <u>315</u>	168.001	150.288	178.399	133.115	92.491	121.257	144.126	97.05	36.16	71.13	43.09	65.45	42.12	55.66	42.18	65.45	42.12	71.

Online results submission

many numerical values



Online results submission

Grade = Quality of the work + + Quality of the submission

Impedance Matching Impedance Matching with Stubs

Smith chart, r=1 and g=1



Analytical solutions

Exam / Project

Case 1, Shunt Stub

Shunt Stub



Matching, series line + shunt susceptance



Analytical solution, usage

$$\cos(\varphi + 2\theta) = -|\Gamma_{S}|$$

$$\theta_{sp} = \beta \cdot l = \tan^{-1} \frac{\mp 2 \cdot |\Gamma_{S}|}{\sqrt{1 - |\Gamma_{S}|^{2}}}$$

 $|\Gamma_s| = 0.593; \quad \varphi = 46.85^\circ \qquad \cos(\varphi + 2\theta) = -0.593 \Rightarrow (\varphi + 2\theta) = \pm 126.35^\circ$

- The sign (+/-) chosen for the series line equation imposes the sign used for the shunt stub equation
 - "+" solution $(46.85^{\circ} + 2\theta) = +126.35^{\circ}$ $\theta = +39.7^{\circ}$ Im $y_s = \frac{-2 \cdot |\Gamma_s|}{\sqrt{1 - |\Gamma_s|^2}} = -1.472$ $\theta_{sp} = \tan^{-1}(\operatorname{Im} y_s) = -55.8^{\circ}(+180^{\circ}) \rightarrow \theta_{sp} = 124.2^{\circ}$

Solution
(46.85°+2θ) = −126.35°
$$θ = -86.6°(+180°) → θ = 93.4°$$

Im $y_s = \frac{+2 \cdot |\Gamma_s|}{\sqrt{1 - |\Gamma_s|^2}} = +1.472$ $θ_{sp} = tan^{-1}(Im y_s) = 55.8°$

Analytical solution, usage

$$(\varphi + 2\theta) = \begin{cases} +126.35^{\circ} \\ -126.35^{\circ} \end{cases} \theta = \begin{cases} 39.7^{\circ} \\ 93.4^{\circ} \end{cases} \operatorname{Im}[y_{s}(\theta)] = \begin{cases} -1.472 \\ +1.472 \end{cases} \theta_{sp} = \begin{cases} -55.8^{\circ} + 180^{\circ} = 124.2^{\circ} \\ +55.8^{\circ} \end{cases}$$

We choose one of the two possible solutions
 The sign (+/-) chosen for the series line equation imposes the sign used for the shunt stub equation

$$l_{1} = \frac{39.7^{\circ}}{360^{\circ}} \cdot \lambda = 0.110 \cdot \lambda$$

$$l_{1} = \frac{93.4^{\circ}}{360^{\circ}} \cdot \lambda = 0.259 \cdot \lambda$$

$$l_{2} = \frac{124.2^{\circ}}{360^{\circ}} \cdot \lambda = 0.345 \cdot \lambda$$

$$l_{2} = \frac{55.8^{\circ}}{360^{\circ}} \cdot \lambda = 0.155 \cdot \lambda$$

$$l_{2} = \frac{55.8^{\circ}}{360^{\circ}} \cdot \lambda = 0.155 \cdot \lambda$$

$$l_{2} = \frac{1000}{360^{\circ}} \cdot \lambda = 0.155 \cdot \lambda$$

Case 2, Series Stub

- Series Stub
- difficult to realize in single conductor line technologies (microstrip)



Matching, series line + series reactance



Analytical solution, usage

$$\cos(\varphi + 2\theta) = |\Gamma_s|$$

$$\theta_{ss} = \beta \cdot l = \cot^{-1} \frac{\mp 2 \cdot |\Gamma_s|}{\sqrt{1 - |\Gamma_s|^2}}$$

 $\Gamma_{\rm s} = 0.555 \angle -29.92^{\circ}$ $|\Gamma_s| = 0.555; \quad \varphi = -29.92^\circ \qquad \cos(\varphi + 2\theta) = 0.555 \Rightarrow (\varphi + 2\theta) = \pm 56.28^\circ$

- The sign (+/-) chosen for the series line equation imposes the sign used for the series stub equation
 - "+" solution $\begin{array}{l} \textbf{``+`' Solution} \\ (-29.92^{\circ} + 2\theta) = +56.28^{\circ} \\ \theta = 43.1^{\circ} \\ \textbf{Im} z_{s} = \frac{+2 \cdot |\Gamma_{s}|}{\sqrt{1 - |\Gamma_{s}|^{2}}} = +1.335 \\ \theta_{ss} = -\cot^{-1}(\textbf{Im} z_{s}) = -36.8^{\circ}(+180^{\circ}) \rightarrow \theta_{ss} = 143.2^{\circ} \end{array}$
 - "-" solution
 - "-" solution $(-29.92^{\circ} + 2\theta) = -56.28^{\circ}$ $\theta = -13.2^{\circ}(+180^{\circ}) \rightarrow \theta = 166.8^{\circ}$ $\operatorname{Im} z_{s} = \frac{-2 \cdot |\Gamma_{s}|}{\sqrt{1 - |\Gamma_{s}|^{2}}} = -1.335 \qquad \theta_{ss} = -\cot^{-1}(\operatorname{Im} z_{s}) = 36.8^{\circ}$

Analytical solution, usage

$$(\varphi + 2\theta) = \begin{cases} +56.28^{\circ} \\ -56.28^{\circ} \end{cases} \theta = \begin{cases} 43.1^{\circ} \\ 166.8^{\circ} \end{cases} \operatorname{Im}[z_{s}(\theta)] = \begin{cases} +1.335 \\ -1.335 \end{cases} \theta_{ss} = \begin{cases} -36.8^{\circ} + 180^{\circ} = 143.2^{\circ} \\ +36.8^{\circ} \end{cases}$$

We choose one of the two possible solutions
 The sign (+/-) chosen for the series line equation imposes the sign used for the series stub equation

$$l_{1} = \frac{43.1^{\circ}}{360^{\circ}} \cdot \lambda = 0.120 \cdot \lambda$$

$$l_{2} = \frac{143.2^{\circ}}{360^{\circ}} \cdot \lambda = 0.398 \cdot \lambda$$

$$l_{2} = \frac{143.2^{\circ}}{360^{\circ}} \cdot \lambda = 0.398 \cdot \lambda$$

$$l_{2} = \frac{36.8^{\circ}}{360^{\circ}} \cdot \lambda = 0.102 \cdot \lambda$$

$$l_{2} = \frac{36.8^{\circ}}{360^{\circ}} \cdot \lambda = 0.102 \cdot \lambda$$

$$l_{2} = \frac{36.8^{\circ}}{360^{\circ}} \cdot \lambda = 0.102 \cdot \lambda$$

$$l_{2} = \frac{36.8^{\circ}}{360^{\circ}} \cdot \lambda = 0.102 \cdot \lambda$$

Stub, observations

 adding or subtracting 180° (λ/2) doesn't change the result (full rotation around the Smith Chart)

$$E = \beta \cdot l = \pi = 180^{\circ}$$
 $l = k \cdot \frac{\lambda}{2}, \forall k \in \mathbb{N}$

- if the lines/stubs result with negative "length"/ "electrical length" we add λ/2 / 180° to obtain physically realizable lines
- adding or subtracting 90° (λ/4) change the stub impedance:

$$Z_{in,sc} = j \cdot Z_0 \cdot \tan \beta \cdot l \quad \Leftrightarrow \quad Z_{in,g} = -j \cdot Z_0 \cdot \cot \beta \cdot l$$

 for the stub we can add or subtract 90° (λ/4) while in the same time changing open-circuit ⇔ short-circuit

Microwave Amplifiers

Amplifier as two-port



Power / Matching

 Two ports in which matching influences the power transfer



Two-Port Power Gains



Unilateral transducer power gain

$$G_{TU} = |S_{21}|^{2} \cdot \frac{1 - |\Gamma_{S}|^{2}}{|1 - S_{11} \cdot \Gamma_{S}|^{2}} \cdot \frac{1 - |\Gamma_{L}|^{2}}{|1 - S_{22} \cdot \Gamma_{L}|^{2}}$$

$$S_{12} \cong 0 \qquad \qquad \Gamma_{in} = S_{11}$$

Input and output can be treated independently

Microwave Amplifiers



Amplifier as two-port



- For an amplifier two-port we are interested in:
 - stability
 - power gain
 - noise (sometimes small signals)
 - linearity (sometimes large signals)

Microwave Amplifiers

Power Gain of Microwave Amplifiers

Amplifier as two-port



- For an amplifier two-port we are interested in:
 - stability

power gain

- noise (sometimes small signals)
- linearity (sometimes large signals)

Design for Maximum Gain



Simultaneous matching

$$\Delta \cdot \left(S_{11}^{*} \cdot S_{22}^{*} - S_{12}^{*} \cdot S_{21}^{*}\right) = |\Delta|^{2}$$

$$\Gamma_{S}^{2} \cdot \left(S_{11} - \Delta \cdot S_{22}^{*}\right) + \Gamma_{S} \cdot \left(|\Delta|^{2} - |S_{11}|^{2} + |S_{22}|^{2} - 1\right) + \left(S_{11}^{*} - \Delta^{*} \cdot S_{22}\right) = 0$$
• A quadratic equation
$$\Gamma_{S} = \frac{B_{1} \pm \sqrt{B_{1}^{2} - 4 \cdot |C_{1}|^{2}}}{2 \cdot C_{1}}$$
• Similarly
$$\Gamma_{L} = \frac{B_{2} \pm \sqrt{B_{2}^{2} - 4 \cdot |C_{2}|^{2}}}{2 \cdot C_{2}}$$
• With variables defined as:
$$\begin{cases} B_{1} = 1 + |S_{11}|^{2} - |S_{22}|^{2} - |\Delta|^{2} \\ C_{1} = S_{11} - \Delta \cdot S_{22}^{*} \end{cases} \begin{cases} B_{2} = 1 + |S_{22}|^{2} - |S_{11}|^{2} - |\Delta|^{2} \\ C_{2} = S_{22} - \Delta \cdot S_{11}^{*} \end{cases}$$

Simultaneous matching

 Simultaneous matching can be achieved if and only if the amplifier is unconditionally stable at the operating frequency, and |Γ|<1 solutions are those with "–" sign of quadratic solutions

$$\begin{split} \Gamma_{S} &= \frac{B_{1} - \sqrt{B_{1}^{2} - 4 \cdot \left|C_{1}\right|^{2}}}{2 \cdot C_{1}} & \Gamma_{L} &= \frac{B_{2} - \sqrt{B_{2}^{2} - 4 \cdot \left|C_{2}\right|^{2}}}{2 \cdot C_{2}} \\ \begin{cases} B_{1} &= 1 + \left|S_{11}\right|^{2} - \left|S_{22}\right|^{2} - \left|\Delta\right|^{2} & \begin{cases} B_{2} &= 1 + \left|S_{22}\right|^{2} - \left|S_{11}\right|^{2} - \left|\Delta\right|^{2} \\ C_{1} &= S_{11} - \Delta \cdot S_{22}^{*} \end{cases} & \begin{cases} B_{2} &= 1 + \left|S_{22}\right|^{2} - \left|S_{11}\right|^{2} - \left|\Delta\right|^{2} \\ C_{2} &= S_{22} - \Delta \cdot S_{11}^{*} \end{cases} \end{split}$$
Maximum Available Gain

Indicator across full frequency range of the capability to obtain a power gain



MAG/MSG

ATF-34143 at Vds=3V Id=20mA.
 @0.5÷18GHz



Microwave Amplifiers

Design for Specified Gain

Design for Specified Gain

Assumes the amplifier device unilateral

Maximum power gain

$$\Gamma_{S} = S_{11}^{*} \qquad G_{TU \max} = \frac{1}{1 - |S_{11}|^{2}} \cdot |S_{21}|^{2} \cdot \frac{1}{1 - |S_{22}|^{2}}$$
$$\Gamma_{L} = S_{22}^{*}$$

Unilateral figure of merit

 Allows estimation of the error introduced by the unilateral assumption

$$\frac{1}{\left(1+U\right)^{2}} < \frac{G_{T}}{G_{TU}} < \frac{1}{\left(1-U\right)^{2}} \qquad \qquad U = \frac{|S_{12}| \cdot |S_{21}| \cdot |S_{11}| \cdot |S_{22}|}{\left(1-|S_{11}|^{2}\right) \cdot \left(1-|S_{22}|^{2}\right)}$$

- We compute U then the maximum and minimum deviation of G_{TU} from G_T
 - this deviation must be accounted in the design as a reserve gain against the target gain

 $-20 \cdot \log(1+U) < G_T[dB] - G_{TU}[dB] < -20 \cdot \log(1-U)$

Design for Specified Gain



In the unilateral assumption:



$G_{S}(\Gamma_{S})$



 $G_{S} = \frac{1 - \left| \Gamma_{S} \right|^{2}}{\left| 1 - S_{11} \cdot \Gamma_{S} \right|^{2}}$

Re Γ_s

$G_{s}(\Gamma_{s})$, constant value contours

Contour map/lines

© 2011 Encyclopædia Britannica, Inc.

106°

108°

110°

114°

116° E

$G_{s}[dB](\Gamma_{s})$, constant value contours

ADS

Circles are plotted for requested values (in dB!)
 It is usefull to compute G_{Smax} and G_{Lmax} before

in order to request relevant circles

Microwave Amplifiers

Low-Noise Amplifier Design

Amplifier as two-port

- For an amplifier two-port we are interested in:
 - stability
 - power gain
 - noise (sometimes small signals)
 - linearity (sometimes large signals)

Noise

Noise

$$V_{n(ef)} = \sqrt{4kTBR}$$

 noise power available (for maximum power transfer with impedance/resistance matching)
 P_n = kTB

The noise figure F, is a measure of the reduction in signalto-noise ratio between the input and output of a device, when (by definition) the input noise power is assumed to be the noise power resulting from a matched resistor at To = 290 K (reference noise conditions)

$$F = \frac{S_i / N_i}{S_o / N_o} \bigg|_{T_0 = 290K} \qquad V_{n(ef)} = \sqrt{4kTBR} \\ P_n = kTB$$

 The noise figure F, is not directly a measure of the reduction in signal-to-noise ratio between the input and output of a device, when the input noise power is different from that of the reference noise conditions

$$F \neq \frac{S_i / N_i}{S_o / N_o} \bigg|_{T_0 \neq 290K}$$

- In general, the output noise power consists of two elements:
 - the input noise power amplified or attenuated by the device (for example amplified with the power gain G applied also to the desired signal)
 - a noise power generated internally by the network if the network is noisy (this power does not depend on the input noise power)

 Estimation of the internally generated noise power can be done using the Noise Figure F definition:

$$F = \frac{S_1 / N_1}{S_2 / N_2} \bigg|_{T_0 = 290 K, N_1 = N_0}$$

$$N_2 = F \cdot N_0 \cdot \frac{S_2}{S_1} = F \cdot N_0 \cdot G$$
$$N_2 = N_0 \cdot G + (F - 1) \cdot N_0 \cdot G$$

Noise figure of a cascaded system

$$P_{1} = S_{1} + N_{1}$$

$$F_{1}$$

$$F_{1}$$

$$F_{1}$$

$$F_{2}$$

$$F_{2$$

$$P_1 = S_1 + N_1$$

$$F_{cas}$$

$$F_{cas}$$

$$F_{cas}$$

$$\begin{split} N_{2} &= N_{1} \cdot G_{1} + (F_{1} - 1) \cdot N_{0} \cdot G_{1} & G_{cas} = G_{1} \cdot G_{2} \\ N_{3} &= N_{2} \cdot G_{2} + (F_{2} - 1) \cdot N_{0} \cdot G_{2} & N_{3} = N_{1} \cdot G_{cas} + (F_{cas} - 1) \cdot N_{0} \cdot G_{cas} \\ \downarrow \\ N_{3} &= \begin{bmatrix} N_{1} \cdot G_{1} + (F_{1} - 1) \cdot N_{0} \cdot G_{1} \end{bmatrix} \cdot G_{2} + (F_{2} - 1) \cdot N_{0} \cdot G_{2} \\ N_{3} &= N_{1} \cdot G_{1} \cdot G_{2} + (F_{1} - 1) \cdot N_{0} \cdot G_{1} \cdot G_{2} + (F_{2} - 1) \cdot N_{0} \cdot G_{2} \end{split}$$

Noise figure of a cascaded system

$$P_{1} = S_{1} + N_{1}$$

$$F_{1}$$

$$F_{1}$$

$$T_{e1}$$

$$P_{2} = S_{2} + N_{2}$$

$$G_{2}$$

$$F_{2}$$

$$F_{2}$$

$$T_{e2}$$

$$P_{3} = S_{3} + N_{3}$$

$$P_1 = S_1 + N_1$$

$$F_{cas}$$

$$F_{cas}$$

$$F_{cas}$$

$$\begin{split} N_{3} &= N_{1} \cdot G_{1} \cdot G_{2} + (F_{1} - 1) \cdot N_{0} \cdot G_{1} \cdot G_{2} + (F_{2} - 1) \cdot N_{0} \cdot G_{2} \\ G_{cas} &= G_{1} \cdot G_{2} \qquad N_{3} = N_{1} \cdot G_{cas} + (F_{cas} - 1) \cdot N_{0} \cdot G_{cas} \\ (F_{1} - 1) \cdot N_{0} \cdot G_{1} \cdot G_{2} + (F_{2} - 1) \cdot N_{0} \cdot G_{2} = (F_{cas} - 1) \cdot N_{0} \cdot G_{1} \cdot G_{2} \\ F_{cas} &= F_{1} + \frac{1}{G_{1}} (F_{2} - 1) \end{split}$$

Noise figure of a cascaded system

Friis Formula (!linear scale)

$$F_{cas} = F_1 + \frac{F_2 - 1}{G_1} + \frac{F_3 - 1}{G_1 \cdot G_2} + \frac{F_4 - 1}{G_1 \cdot G_2 \cdot G_3} + \cdots$$

Friis Formula (noise)

$$F_{cas} = F_1 + \frac{F_2 - 1}{G_1} + \frac{F_3 - 1}{G_1 \cdot G_2} + \frac{F_4 - 1}{G_1 \cdot G_2 \cdot G_3} + \cdots$$

Friis Formula shows that:

- the overall noise figure of a cascaded system is largely determined by the noise characteristics of the first stage
- the noise introduced by the following stages is reduced:
 - -1
 - division by G (usually G > 1)

Friis Formula (noise)

$$F_{cas} = F_1 + \frac{F_2 - 1}{G_1} + \frac{F_3 - 1}{G_1 \cdot G_2} + \frac{F_4 - 1}{G_1 \cdot G_2 \cdot G_3} + \cdots$$

- Effects of Friis Formula:
- in multi stage amplifiers:
 - it's essential that the first stage is as noiseless as possible even if that means sacrificing power gain
 - the following stages can be optimized for power gain
- in single stage amplifiers:
 - in the input matching circuit it's important to have noiseless elements (pure reactance, lossless lines)
 - output matching circuit has less influence on the noise (noise generated at this level appears when the desired signal has already been amplified by the transistor)

$$V_{n(ef)} = \sqrt{4kTBR}$$
 $P_n = kTB$

Noise Figure of a Mismatched Amplifier

• An input mismatched amplifier($\Gamma \neq o$)

Example

- ATF-34143 at Vds=3V Id=20mA.
- $a_{5}GHz$ IATF-34

 $S11 = 0.64 \angle 139^{\circ}$ # ghz s I

 $S11 = 0.119 \angle -21^{\circ}$ 2.0 0.7

 $S12 = 0.119 \angle -21^{\circ}$ 3.0 0.60
 - S21 = 3.165 ∠16°
 - S22 = 0.22 ∠146°
 - Fmin = 0.54 (tipic [dB]
 - Γ_{opt} = 0.45 ∠174°
 - r_n = 0.03

10.0 1.16 0.61 -43 0.46

Example

Stabilization, input series resistor

freq, GHz

Stabilization, input shunt resistor

freq, GHz

Stabilization, output series resistor

freq, GHz

freq, GHz

 $R_{SL} = 1 \div 10 \Omega$

Stabilization, output shunt resistor

Noise figure of a two-port amplifier

3 noise parameters (2reals + 1 complex):

$$F_{\min}, r_n = \frac{R_N}{Z_0}, \Gamma_{opt}$$

$$F = F_{\min} + \frac{R_N}{G_S} \cdot |Y_S - Y_{opt}|^2 \qquad Y_S = \frac{1}{Z_0} \cdot \frac{1 - \Gamma_S}{1 + \Gamma_S} \qquad Y_{opt} = \frac{1}{Z_0} \cdot \frac{1 - \Gamma_{opt}}{1 + \Gamma_{opt}}$$

$$F = F_{\min} + 4 \cdot r_n \cdot \frac{|\Gamma_S - \Gamma_{opt}|^2}{(1 - |\Gamma_S|^2) \cdot |1 + \Gamma_{opt}|^2}$$
• Γ_{opt} optimum source reflection coefficient that results in minimum noise figure
$$\Gamma_S = \Gamma_{opt} \Rightarrow F = F_{\min}$$

F(Γ_S)

$F[dB](\Gamma_s)$

$F[dB](\Gamma_s)$, constant value contours



$G_{s}[dB](\Gamma_{s})$, constant value contours



$$F = F_{\min} + 4 \cdot r_n \cdot \frac{\left|\Gamma_s - \Gamma_{opt}\right|^2}{\left(1 - \left|\Gamma_s\right|^2\right) \cdot \left|1 + \Gamma_{opt}\right|^2}$$

• We define N (noise figure parameter)
• N constant for F constant

$$N = \frac{\left|\frac{\Gamma_s - \Gamma_{opt}\right|^2}{1 - \left|\Gamma_s\right|^2} = \frac{F - F_{\min}}{4 \cdot r_n} \cdot \left|1 + \Gamma_{opt}\right|^2$$

$$\left(\Gamma_s - \Gamma_{opt}\right) \cdot \left(\Gamma_s^* - \Gamma_{opt}^*\right) = N \cdot \left(1 - \left|\Gamma_s\right|^2\right)$$

$$\Gamma_s \cdot \Gamma_s^* + N \cdot \left|\Gamma_s\right|^2 - \left(\Gamma_s \cdot \Gamma_{opt}^* - \Gamma_s^* \cdot \Gamma_{opt}\right) + \Gamma_{opt} \cdot \Gamma_{opt}^* = N$$

$$\Gamma_s \cdot \Gamma_s^* - \frac{\Gamma_s \cdot \Gamma_{opt}^* - \Gamma_s^* \cdot \Gamma_{opt}}{N + 1} + \Gamma_{opt} \cdot \Gamma_{opt}^* = \frac{N - \left|\Gamma_{opt}\right|^2}{N + 1} + \frac{\left|\Gamma_{opt}\right|^2}{(N + 1)^2}$$

$$|a + b|^2 = (a + b) \cdot (a + b)^* = (a + b) \cdot (a^* + b^*) = |a|^2 + |b|^2 + a^* \cdot b + a \cdot b^*$$



$$\begin{vmatrix} \Gamma_{S} - \frac{\Gamma_{opt}}{N+1} \end{vmatrix} = \frac{\sqrt{N \cdot \left(N + 1 - \left|\Gamma_{opt}\right|^{2}\right)}}{N+1} \qquad N = \frac{F - F_{\min}}{4 \cdot r_{n}} \cdot \left|1 + \Gamma_{opt}\right|^{2}}{\sqrt{N \cdot \left(N + 1 - \left|\Gamma_{opt}\right|^{2}\right)}} \\ |\Gamma_{S} - C_{F}| = R_{F} \qquad C_{F} = \frac{\Gamma_{opt}}{N+1} \qquad R_{F} = \frac{\sqrt{N \cdot \left(N + 1 - \left|\Gamma_{opt}\right|^{2}\right)}}{N+1} \end{aligned}$$

- The locus in the complex plane Γ_s of the points with constant noise figure is a circle
- Interpretation: Any reflection coefficient Γ_s which plotted in the complex plane lies on the circle drawn for F_{circle} will lead to a noise factor F = F_{circle}
 - Any reflection coefficient Γ_S plotted **outside** this circle will lead to a noise factor F > F_{circle}
 - Any reflection coefficient Γ_s plotted inside this circle will lead to a noise factor F < F_{circle}

ADS



- The noise internally generated by the transistor depends only by the input matching circuit
- A minimum noise figure is possible (NF_{min} a datasheet/"s2p file" parameter for the transistor)
- If we design a low noise amplifier (LNA) the usual design technique is as follows:
 - design of the input matching circuit solely (largely) for noise optimization
 - design of output matching circuit for gain compensation/optimization (if lossy circuits are used the output matching circuit noise can be added but the transistor noise is not influenced)

LNA – Low Noise Amplifier

 Usually a transistor suitable for implementing an LNA at a certain frequency will have input gain circles and noise circles in the same area for Γ_s



- Connecting the amplifier (transistor) directly to the source with Zo generate a reflection coefficient seen towards the source equal with **o** (complex number, $\Gamma_o = o + o \cdot j$)
 - most of the time this reflection coefficient does not offer optimum noise/gain



- We plot on the complex plane (Smith Chart) the stability/gain/noise circles (depending on the particular application)
- We choose a point with a suitable position relative to these circles (also application dependent)
- We determine the input reflection coefficient corresponding to this point, $\Gamma_{\rm S}$



 We insert the input matching circuits which allows the transistor to see towards the source the previously determined reflection coefficient Γ_s



- Easiest to design matching section consists in the insertion of (in order from the transistor towards the Z_o source):
 - a series Z_o line, with electrical length θ
 - a shunt stub, open-circuited, made from a Z_o line, with electrical length θ_{sp}



• Computation depends solely on $\Gamma_{\rm S}$ (magnitude and phase) $\mp 2 \cdot |\Gamma_{\rm S}|$

$$\cos(\varphi_{s}+2\theta) = -|\Gamma_{s}| \qquad \tan \theta_{sp} = -$$

The sign (+/-) chosen for the series line equation imposes the sign used for the shunt stub equation



Shunt stub matching, L7



Example, LNA @ 5 GHz

- ATF-34143 at Vds=3V Id=20mA.
- 35GHz• $511 = 0.64 \angle 139^{\circ}$ • $512 = 0.119 \angle -21^{\circ}$ • $521 = 3.165 \angle 16^{\circ}$ • 14TF-34143• 15-PARAMETER# ghz s mar 502.0 0.75 -1262.5 0.72 -1453.0 0.69 -1624.0 0.65 1147.0 0.65 89 2
 - S22 = 0.22 ∠146°
 - Fmin = 0.54 (tipic [dB]
 - Γ_{opt} = 0.45 ∠174°
 - r_n = 0.03

_	
	!ATF-34143 !S-PARAMETERS at Vds=3V Id=20mA. LAST UPDATED 01-29-99
	# ghz s ma r 50
	2.0 0.75 -126 6.306 90 0.088 23 0.26 -120 2.5 0.72 -145 5.438 75 0.095 15 0.25 -140 3.0 0.69 -162 4.762 62 0.102 7 0.23 -156
→	4.0 0.65 166 3.806 38 0.111 -8 0.22 174 5.0 0.64 139 3.165 16 0.119 -21 0.22 146 6.0 0.65 114 2.706 -5 0.125 -35 0.23 118
	7.0 0.66 89 2.326 -27 0.129 -49 0.25 91 8.0 0.69 67 2.017 -47 0.133 -62 0.29 67 9.0 0.72 48 1.758 -66 0.135 -75 0.34 46
B]	!FREQ Fopt GAMMA OPT RN/Zo !GHZ dB MAG ANG -
	2.0 0.19 0.71 66 0.09 2.5 0.23 0.65 83 0.07 3.0 0.29 0.59 102 0.06
\rightarrow	4.0 0.42 0.51 138 0.03 5.0 0.54 0.45 174 0.03
	6.0 0.67 0.42 -151 0.05 7.0 0.79 0.42 -118 0.10 8.0 0.92 0.45 -88 0.18
	9.0 1.04 0.51 -63 0.30

100 1 16 0 61 -43 0 46

Example, LNA @ 5 GHz

- Low Noise Amplifier
- At the input matching a compromise is required between:
 - noise (input constant noise figure circles)
 - gain (input constant gain circles)
 - stability (input stability circle)
- At the output matching noise is not influenced.
 A compromise is required between :
 - gain (output constant gain circles)
 - stability (output stability circle)

Example, LNA @ 5 GHz



- In this particular case G_{Lmax} = 0.21 dB, the transistor could be used directly connected to the 50Ω load
- The absence of the output matching circuit is not recommended. While the attainable power gain is low, it's absence eliminates the possibility to use it to compensate an improper gain generated by the noise optimization of the input matching circuit

Input matching circuit



- For the input matching circuit
 - noise circle CZ: 0.75dB
 - input constant gain circles CCCIN: 1dB, 1.5dB, 2 dB
- We choose (small $Q \rightarrow$ wide bandwidth) position m1

Input matching circuit



 If we can afford a 1.2dB decrease of the input gain for better NF,Q (Gs = 1 dB), position m1 above is better
 We obtain better (smaller) NF

Input matching circuit

• Position m1 in complex plane (Smith Chart) $\Gamma_{S} = 0.412 \angle -178^{\circ}$ $|\Gamma_{S}| = 0.412; \quad \varphi = -178^{\circ}$ $\cos(\varphi + 2\theta) = -|\Gamma_{S}|$ $\operatorname{Im}[y_{S}(\theta)] = \frac{\mp 2 \cdot |\Gamma_{S}|}{\sqrt{1 - |\Gamma_{S}|^{2}}}$ $\cos(\varphi + 2\theta) = -0.412 \Rightarrow (\varphi + 2\theta) = \pm 114.33^{\circ}$

$$(\varphi + 2\theta) = \begin{cases} +114.33^{\circ} \\ -114.33^{\circ} \end{cases} \theta = \begin{cases} 146.2^{\circ} \\ 31.8^{\circ} \end{cases} \operatorname{Im}[y_{S}(\theta)] = \begin{cases} -0.904 \\ +0.904 \end{cases} \theta_{sp} = \begin{cases} 137.9^{\circ} \\ 42.1^{\circ} \end{cases}$$

Output matching circuit



output constant gain circles CCCOUT: -0.4dB, -0.2dB, odB, +0.2dB
 the lack of noise restrictions allows optimization for better gain (close to maximum – position m4)

Output matching circuit

• Position m4 in complex plane (Smith Chart) $\Gamma_L = 0.186 \angle -132.9^\circ$ $|\Gamma_L| = 0.186; \quad \varphi = -132.9^\circ$ $\cos(\varphi + 2\theta) = -|\Gamma_L|$ $\operatorname{Im}[y_L(\theta)] = \frac{-2 \cdot |\Gamma_L|}{\sqrt{1 - |\Gamma_L|^2}} = -0.379$ $\cos(\varphi + 2\theta) = -0.186 \Rightarrow (\varphi + 2\theta) = \pm 100.72^\circ$

$$(\varphi + 2\theta) = \begin{cases} +100.72^{\circ} \\ -100.72^{\circ} \end{cases} \theta = \begin{cases} 116.8^{\circ} \\ 16.1^{\circ} \end{cases} \operatorname{Im}[y_{L}(\theta)] = \begin{cases} -0.379 \\ +0.379 \end{cases} \theta_{sp} = \begin{cases} 159.3^{\circ} \\ 20.7^{\circ} \end{cases}$$

LNA

 We estimate a gain (in unilateral assumption, ±0.9 dB)

 $G_{T}[dB] = G_{S}[dB] + G_{0}[dB] + G_{L}[dB]$ $G_{T}[dB] = 1 dB + 10 dB + 0.2 dB = 11.2 dB$

 We estimate a noise factor well bellow 0.75dB (quite close to the minimum ~0.6 dB)

ADS





ADS





freq, GHz

Microwave Filters



 this structure is frequently encountered in radiocommunication systems



Microwave Filters

- Two ways of implementing filters in microwave frequency range
 - microwave specific structures (coupled lines, dielectric resonators, periodic structures)
 - filter synthesis with lumped elements followed by implementation with transmission lines
- the first strategy leads to more efficient filters but:
 - has lower generality
 - design is often difficult (lack of analytical relationships)

Filter synthesis

- Filter is designed with lumped elements (L/C) followed by implementation with distributed elements (transmission lines)
 - general
 - analytical relationships easy to implement on the computer
 - efficient
- The preferred procedure is insertion loss method

Insertion loss method

$$P_{LR} = \frac{P_S}{P_L} = \frac{1}{1 - \left|\Gamma(\omega)\right|^2}$$

• $|\Gamma(\omega)|^2$ is an even function of ω

$$\left|\Gamma(\omega)\right|^{2} = \frac{M(\omega^{2})}{M(\omega^{2}) + N(\omega^{2})}$$
$$P_{LR} = 1 + \frac{M(\omega^{2})}{N(\omega^{2})}$$

 Choosing M and N polynomials appropriately leads to a filter with a completely specified frequency response

Insertion loss method

- We control the power loss ratio/attenuation introduced by the filter:
 - in the passband (pass all frequencies)
 - in the stopband (reject all frequencies)



Filter specifications



(=1)

Insertion loss method

- We choose the right polynomials to design an low-pass filter (prototype)
- The low-pass prototype are then converted to the desired other types of filters
 - low-pass, high-pass, bandpass, or bandstop



Practical low-pass prototypes responses

- Maximally flat filters (Butterworth, binomial): provide the flattest possible passband response
- Equal ripple filters (Chebyshev): provide a sharper cutoff but the passband response will have ripples
- Elliptic function filters, they have equal-ripple responses in the passband as well as in the stopband,
- Linear phase filters, offer linear phase response in the passband to avoid signal distortion (important in some applications)

Maximally Flat/Equal ripple LPF Prototype



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Elliptic function LPF Prototype


Maximally Flat LPF Prototype

• Polynomial

$$P_{LR} = 1 + k^2 \cdot \left(\frac{\omega}{\omega_c}\right)$$

• For
$$\omega >> \omega_c$$

$$P_{LR} \approx k^2 \cdot (\omega/\omega_c)^{2N}$$



- attenuation increases Figure 8.21 John Wiley & Sons, Inc. All rights reserved.
 at a rate of 20·N dB/decade
- k gives the attenuation at cutoff frequency (3dB cutoff imposes k = 1)

Equal Ripple LPF Prototype

Polynomial

$$P_{LR} = 1 + k^2 \cdot T_N^2 \left(\frac{\omega}{\omega_c}\right)$$

- For $\omega >> \omega_c$ $P_{LR} \approx \frac{k^2}{4} \cdot \left(\frac{2 \cdot \omega}{\omega_c}\right)^{2N}$
- attenuation increases
 ¹0
 ¹0
- attenuation is (2^{2N})/4 greater than the binomial response at any given frequency where $\omega >> \omega_c$
- the passband ripples: 1 + k², k gives the ripple



Order (N) of the Maximally Flat filter

$$n \ge \frac{\log \left(\frac{\frac{L_{As}}{10} - 1}{\frac{L_{Ar}}{10} - 1}\right)}{2 \cdot \log \frac{\omega'_s}{\omega'_1}}$$

Iattenuations in dB



Order (N) of the Equal Ripple filter



Maximally flat filter prototypes



3 dB Equal-ripple filter prototypes



o.5 dB Equal-ripple filter prototypes



Prototype Filters



(a)



Prototype Filters

- Prototype filters are:
 - Low-Pass Filters (LPF)
 - cutoff frequency $\omega_0 = 1 \text{ rad/s} (f_0 = 0.159 \text{ Hz})$
 - connected to a source with R = 1Ω
- The number of reactive elements (L/C) is the order of the filter (N)
- Reactive elements are alternated: series L / shunt C
- There two prototypes with the same response, a prototype beginning with a shunt C element, and a prototype beginning with a series L element

Prototype Filters

We define filter parameters g_i, i=o,N+1
 g_i are the element values in the prototype filter

 $g_{0} = \begin{cases} \text{generator resistance } R'_{0} \text{ if } g_{1} = C'_{1} \\ \text{generator conductance } G'_{0} \text{ if } g_{1} = L'_{1} \end{cases}$

 $g_k|_{k=\overline{1,N}} = \begin{cases} \text{inductance for series inductors} \\ \text{capacitance for shunt capacitors} \end{cases}$

$$g_{N+1} = \begin{cases} \text{load resistance } R'_{N+1} \text{ if } g_N = C'_N \\ \text{load conductance } G'_{N+1} \text{ if } g_N = L'_N \end{cases}$$

Maximally Flat LPF Prototype

Formulas for filter parameters

$$g_0 = 1$$

$$g_k = 2 \cdot \sin \left[\frac{(2 \cdot k - 1) \cdot \pi}{2 \cdot N} \right] , \quad k = 1, N$$

$$g_{N+1} = 1$$

Maximally Flat LPF Prototype

TABLE 8.3 Element Values for Maximally Flat Low-Pass Filter Prototypes ($g_0 = 1$, $\omega_c = 1$, N = 1 to 10)

N	<i>g</i> ₁	<i>g</i> ₂	<i>g</i> ₃	<i>g</i> 4	g 5	g 6	g 7	<i>g</i> 8	g 9	<i>g</i> ₁₀	<i>g</i> ₁₁
1	2.0000	1.0000									
2	1.4142	1.4142	1.0000								
3	1.0000	2.0000	1.0000	1.0000							
4	0.7654	1.8478	1.8478	0.7654	1.0000						
5	0.6180	1.6180	2.0000	1.6180	0.6180	1.0000					
6	0.5176	1.4142	1.9318	1.9318	1.4142	0.5176	1.0000				
7	0.4450	1.2470	1.8019	2.0000	1.8019	1.2470	0.4450	1.0000			
8	0.3902	1.1111	1.6629	1.9615	1.9615	1.6629	1.1111	0.3902	1.0000		
9	0.3473	1.0000	1.5321	1.8794	2.0000	1.8794	1.5321	1.0000	0.3473	1.0000	
10	0.3129	0.9080	1.4142	1.7820	1.9754	1.9754	1.7820	1.4142	0.9080	0.3129	1.0000

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Equal-ripple LPF Prototype

Formulas for filter parameters (iterative)

$$\begin{aligned} a_{k} &= \sin\left[\frac{\left(2\cdot k-1\right)\cdot \pi}{2\cdot N}\right] , \quad k = 1, N \qquad \beta = \ln\left(\coth\frac{L_{Ar}}{17.37}\right) \\ \gamma &= \sinh\left(\frac{\beta}{2\cdot N}\right) \qquad b_{k} = \gamma^{2} + \sin^{2}\left(\frac{k\cdot \pi}{N}\right) , \quad k = 1, N \\ g_{1} &= \frac{2\cdot a_{1}}{\gamma} \\ g_{k} &= \frac{4\cdot a_{k-1}\cdot a_{k}}{b_{k-1}\cdot g_{k-1}} , \quad k = 2, N \\ g_{N+1} &= \begin{cases} 1 & \text{for odd } N \\ \cosh^{2}\left(\frac{\beta}{4}\right) & \text{for even } N \end{cases} \end{aligned}$$

TABLE8.4	Element	Values	for	Equal-Ripple	Low-Pass	Filter	Prototypes	$(g_0 = 1, \omega_c =$
1, N = 1 to 10	, 0.5 dB a	nd 3.0 d	B ri	pple)				

0.5 dB Ripple											
N	<i>g</i> ₁	82	83	84	85	8 6	87	88	89	<i>g</i> ₁₀	<i>g</i> ₁₁
1	0.6986	1.0000									
2	1.4029	0.7071	1.9841								
3	1.5963	1.0967	1.5963	1.0000							_
4	1.6703	1.1926	2.3661	0.8419	1.9841						
5	1.7058	1.2296	2.5408	1.2296	1.7058	1.0000					
6	1.7254	1.2479	2.6064	1.3137	2.4758	0.8696	1.9841				
7	1.7372	1.2583	2.6381	1.3444	2.6381	1.2583	1.7372	1.0000			
8	1.7451	1.2647	2.6564	1.3590	2.6964	1.3389	2.5093	0.8796	1.9841		
9	1.7504	1.2690	2.6678	1.3673	2.7239	1.3673	2.6678	1.2690	1.7504	1.0000	
10	1.7543	1.2721	2.6754	1.3725	2.7392	1.3806	2.7231	1.3485	2.5239	0.8842	1.984
					3.0 dE	8 Ripple					
N	<i>g</i> 1	8 2	83	<i>8</i> 4	85	g 6	87	<i>g</i> 8	<u>89</u>	g10	<i>g</i> 11
1	1.9953	1.0000									
2	3.1013	0.5339	5.8095								
3	3.3487	0.7117	3.3487	1.0000							
4	3.4389	0.7483	4.3471	0.5920	5.8095						
5	3.4817	0.7618	4.5381	0.7618	3.4817	1.0000					
6	3.5045	0.7685	4.6061	0.7929	4.4641	0.6033	5.8095				
7	3.5182	0.7723	4.6386	0.8039	4.6386	0.7723	3.5182	1.0000			
8	3.5277	0.7745	4.6575	0.8089	4.6990	0.8018	4.4990	0.6073	5.8095		
9	3.5340	0.7760	4.6692	0.8118	4.7272	0.8118	4.6692	0.7760	3.5340	1.0000	
10	2 5204	0 7771	1 (7(0	0.0126	1 7 1 2 5	0.9164	1 7260	0 0051	4 51 42	0 (001	5 0004

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 For even N order of the filter (N = 2, 4, 6, 8 ...) equal-ripple filters must closed by
 a load impedance

g_{N+1} ≠ 1
If the application
doesn't allow this,
supplemental
impedance matching
is required (quarterwave transformer,
binomial ...) to g_L = 1

Table 8.4

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Example

 Design a 3rd order bandpass filter with o.5 dB ripples in passband. The center frequency of the filter should be 1 GHz. The fractional bandwidth of the passband should be 10%, and the impedance 50Ω.

LPF Prototype

o.5dB equal-ripple table or design formulas:

- g1 = 1.5963 = L1/C3,
- g2 = 1.0967 = C2/L4,
- g3 = 1.5963 = L3/C5,
- g4=1.000 = R_L

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Term Term1 Num=1 Z=1 Ohm	L L1 L=1.5963 H R=	C C2 C2 C=1.0967 F	L L3 L=1.5963 H R=	Term Term2 Num=2 Z=1 Ohm
Term Term3 Num=3 Z=1 Ohm	C C3 C=1.5963 F	 L L4 L=1.0967 H R=	C C5 C=1.5963 F	Term Term4 Num=4 Z=1 Ohm

LPF Prototype

• $\omega_{o} = 1 \text{ rad/s} (f_{o} = \omega_{o} / 2\pi = 0.159 \text{ Hz})$



Impedance and Frequency Scaling

- After computing prototype filter's elements:
 - Low-Pass Filters (LPF)
 - cutoff frequency $\omega_0 = 1 \text{ rad/s} (f_0 = 0.159 \text{ Hz})$
 - connected to a source with $R = 1\Omega$
- component values can be scaled in terms of impedance and frequency

Impedance and Frequency Scaling

- LPF Prototype is only used as an intermediate step
 - Low-Pass Filter (LPF)
 - cutoff frequency $\omega_0 = 1 \text{ rad/s} (f_0 = 0.159 \text{ Hz})$
 - connected to a source with R = 1Ω



Impedance Scaling

To design a filter which will work with a source resistance of R_o we multiplying all the impedances of the prototype design by R_o (" " denotes scaled values)

$$R'_{s} = R_{0} \cdot (R_{s} = 1) \qquad \qquad R'_{L} = R_{0} \cdot R_{L}$$
$$L' = R_{0} \cdot L \qquad \qquad C' = \frac{C}{R_{0}}$$



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